

**Advance**

03.05.27

◆ Features

- Up to 10.0 Gb/s high speed operation
- 3.3V single Voltage Supply operation
- Differential CML compatible interface
- Disable function of modulation current
- Modulation current monitoring
- Up to 65 mA_{p-p} RF modulation current at an external 25Ω load
or Up to 75 mA_{p-p} RF modulation current at an external 15Ω load
- Up to 100 mA DC bias current
- On-chip 50Ω input terminations
- Internal voltage reference for AC coupling

F0539951Q

10.0Gb/s NRZ Data Rate

Laser Diode Driver

◆ Applications

- Laser diode driver of an optical transmitter circuit up to 10.0 Gb/s

◆ Functional Description

The F0539951Q is a high performance GaAs laser diode driver IC applicable in an optical transmitter circuit up to 10.0 Gb/s NRZ data rate (especially suitable for STM-64 / OC-192).

The F0539951Q specifies the rise time and the fall time of 35 ps (20 % - 80 %, 25Ω load) typically. It features the single 3.3V supply operation, the modulation current between 10 mA_{p-p} and 65 mA_{p-p}, and the bias current between 3 mA and 100 mA.

♦ **Absolute Maximum Ratings**

T_a=25°C, unless specified.

Parameter	Symbol	Value	Units
Supply Voltage (VSS)	VDD - VSS	-0.5 to +4.0	V
Supply Voltage (VSSM)	VDD - VSSM	-0.5 to +4.0	V
Supply Voltage (VSSB)	VDD - VSSB	-0.5 to +6.0	V
Supply Current*1	ISS	180	mA
Supply Current (VSSM)	ISSM	150	mA
Supply Current (VSSB)	ISSB	150	mA
Output Current (OUT, OUTB, BIAS)	IOUT	150	mA
Input Voltage (DIN, DINB)	VIN	VDD - 2.5 to VDD	V
Input Voltage (DIS)	VINC1	VSS - 0.5 to VDD + 0.5	V
Input Voltage (VM)	VINC2	VSS to VSS + 1.5	V
Input Voltage (VB)	VINC3	VSS to VSS + 2.0	V
Output Voltage (OUT, OUTB)	VOUT	VDD - 1.5 to VDD + 1.5	V
Output Voltage (BIAS)	VBIAS	VSSB to VSSB + 3.5V	V
Output Voltage (MODSEN)	VOUTM	VSS to VDD	V
Storage Temperature	Tstg	-55 to + 125	°C

NOTE: *1. Excluding the input current, the modulation current and the bias current.

♦ **Recommended Operating Conditions**

Parameter	Symbol	Value			Unit
		MIN.	TYP.	MAX.	
Supply Voltage	VDD - VSS	3.1	3.3	3.5	V
Output Voltage	VOUT -VDD	-1.0	0	1.0	V
BIAS Output Voltage	VBIAS - VSSB	1.3	1.5	3.0	V
Ambient Operating Temperature	T _a	0	25	70	°C

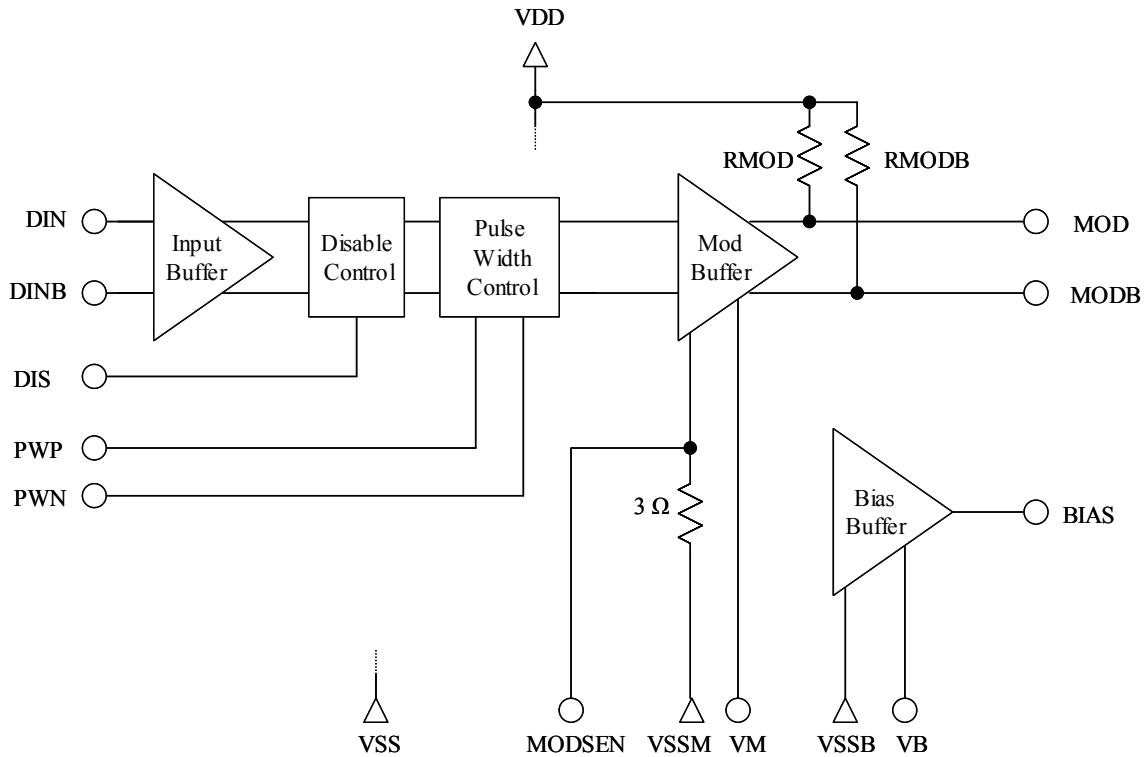
◆ **Electrical Characteristics**

T_a=25°C, V_{DD}-V_{SS} = V_{DD}-V_{SSM} = V_{DD}-V_{SSB} = 3.3V, unless specified

Parameters	Symbol	Test Conditions	Value			Units
			MIN.	TYP.	MAX	
Circuit Current *1	ISS	V _M - V _{SS} =0[V] V _B - V _{SS} =0[V]	-	95	-	mA
Input Voltage (AC coupled interface)	V _{IN}	Differential Input	0.4	0.8	1.6	V _{p-p}
Input Resistor	R _{IN}	Differential	-	100	-	Ω
Modulation Peak Current	I _{Mmax}	25Ω load	-	65	-	mAp-p
	I _{Mmin}	25Ω load, V _M =V _{SS}	-	10	-	mAp-p
	I _{Mdis}	V _{DIS} =V _{DD} - 0.2V	-	2	-	mA
Output Resistor	R _{MOD}		-	50	-	Ω
Bias Current	I _{Bmax}	V _{BIAS} -V _{SSB} =1.3V	100	-	-	mA
	I _{Bmin}	V _{BIAS} -V _{SSB} =1.3V V _B =V _{SS}	-	3	-	mA
Input Voltage of DIS pin	V _{DISih}	Disable operation	V _{DD} - 0.2	-	V _{DD}	V
	V _{DISil}	Enable operation	V _{SS}	OPEN	V _{SS} +0.2	V
Modulation Monitor Resistor	R _{MM}		-	3	-	Ω
Rise Time	T _r	R _L = 25Ω, 20% - 80%	-	35	-	ps
Fall Time	T _f	R _L = 25Ω, 20% - 80%	-	35	-	ps
Maximum Data Rate	fopr		10.0	-	-	Gb/s

NOTE: *1. Excluding the input current, the modulation current and the bias current.

◆ *Block Diagram*



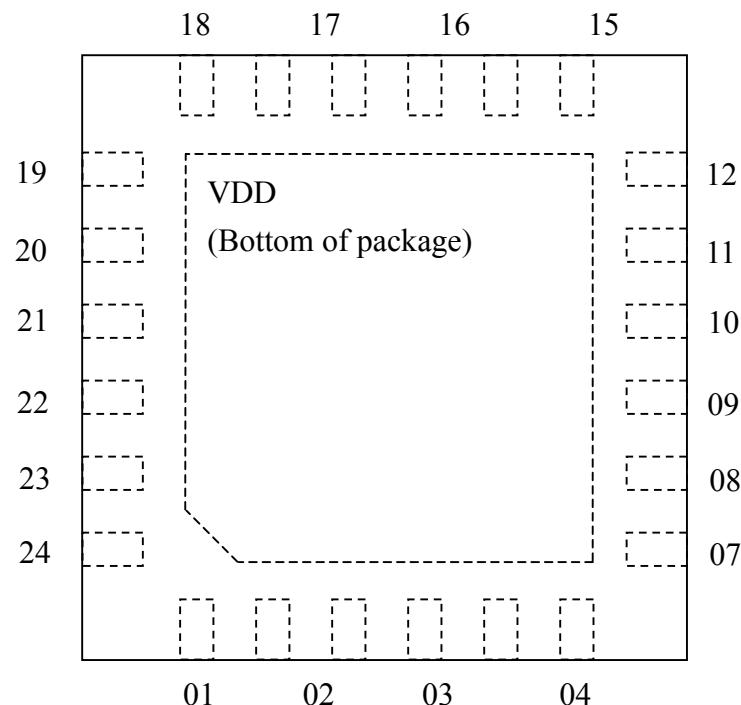
◆ *PAD Descriptions*

Symbol	Description
VDD	Supply Voltage
VSS, VSSM, VSSB	Supply Voltage. VSS, VSSM and VSSB are not connected internally.
DIN	Positive data input
DINB	Negative data input
MOD	Positive modulation output (LD should be connected to this pin.)
MODB	Negatibe modulation output
BIAS	Bias current output
VM	Voltage input that sets the LD modulation peak current
VB	Voltage input that sets the bias current
DIS	Voltage input that controls turning on/off modulation current
PWP, PWN	Pulse Width Control
MODSEN	Modulation current monitor output

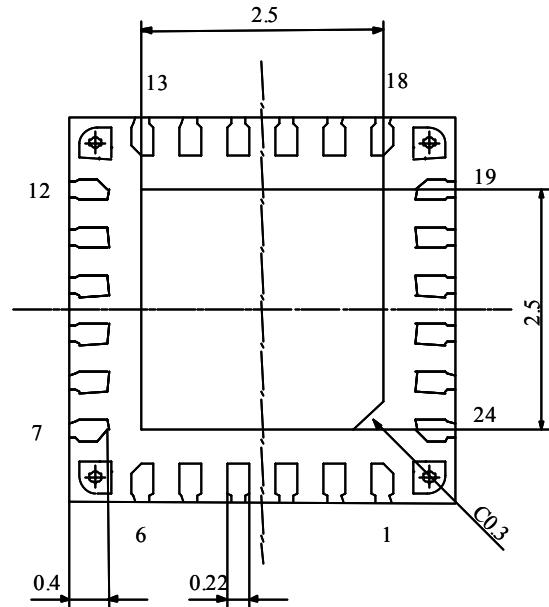
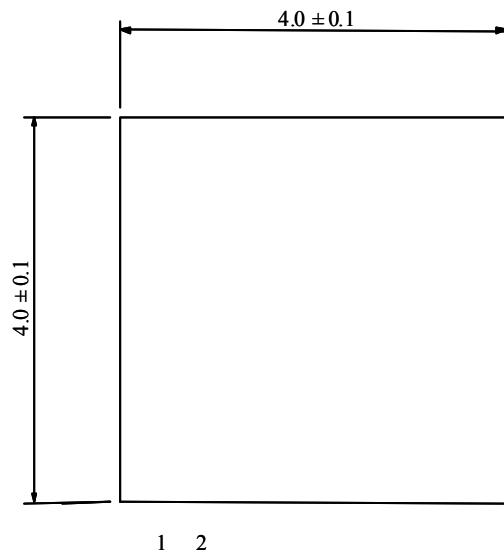
♦ Function Table

INPUT	OUTPUT	
DIN	Current at MOD	Current at MODB
H	ON	OFF
L	OFF	ON

♦ **Package Pin Assignments (Top View)**



Pin No.	Symbol	Pin No.	Symbol
01	VDD	13	VDD
02	DIN	14	VDD
03	VDD	15	MODB
04	DINB	16	VDD
05	VDD	17	MOD
06	VDD	18	VDD
07	DIS	19	BIAS
08	MODSEN	20	VSSB
09	VM	21	VSS
10	VSS	22	VB
11	VSSM	23	PWP
12	NC	24	PWN

♦ Package Drawings

Dimension: millimeters

Top View

Bottom View

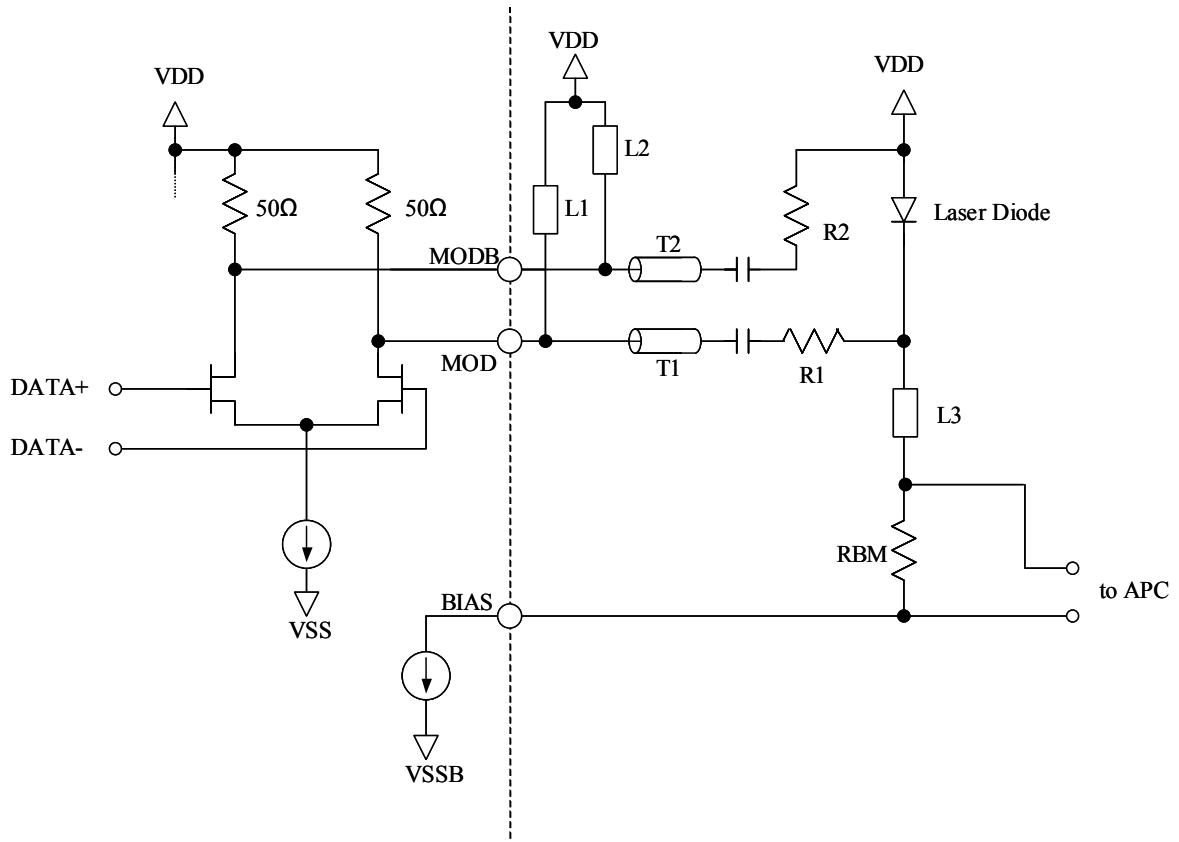
Package Format : 24-pin QFN

Package Size : 4 mm x 4 mm x 0.7 mm

Pin Pitch : 0.5mm

♦ **Typical Connection**

1) Output Stage



NOTE:

- L1, L2, L3 RF Choke Inductor
- R1, R2 5 to 20Ω Damping Resistor
- T1, T2 50Ω or 25Ω transmission lines
- RBM 3 to 5Ω Bias Monitor Resistor

2) Pulse Width control

